Prediction of Formability in Perovskite-Type Oxides

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Abstract: Prediction criterions for the formabilities of perovskite-type oxides are obtained by using the empirical structure map methods constructed by two parameters octahedral factor (r_B/r_O) and tolerance factor, on this structure map, simple point representing systems of forming and non forming are distributed in distinctively different regions. In this paper we found that the octahedral factor, is as important as the tolerance factor with regards to the formability of perovskite-type oxides. We have applied the proposed model to 173 ABO₃ perovskites and it can be used to search for new perovskite-type oxides by screening all possible elemental combinations.

INTRODUCTION

A large number of perovskite-type oxides have been studied because of their interesting properties, including superconductivity, insulator-metal transition, ionic conduction characteristics, dielectric properties and ferroelasticity [1-3]. Additionally, they have received great attention as high temperature proton conductors with the possibility of applications in fuel cells or hydrogen sensors. Perovskite is one of the most frequently encountered structures in solid-state physics, and it accommodates most of the metallic ions in the periodic table with a significant number of different anions. During the last few years, many experimental and theoretical investigations were devoted to the study of perovskite solids: typically ABX₃ (A: large cation with different valence, B: transition metal and X: oxides and halides). These solids are currently gaining considerable importance in the field of electrical ceramics, refractories, geophysics, astrophysics, particle accelerators, fission, fusion reactors, heterogeneous catalysis etc [4-7]. In perovskite structures, which is shown in Fig. (1a), B cations are coordinates by six X anions, while A cations present coordination number 12 (also coordinated by X anions). The X anions have coordination number 2, being coordinated by two B cations, since the distance A-X is about 40% larger than the B-X bond distance. The cubic perovskite is called the ideal perovskite, which is the subject of this study. This class of materials has great potential for a variety of device applications due to their simple crystal structures and unique ferroelectric and dielectric properties [8-15]. As one of the most abundant and widely investigated minerals, perovskites solids are widely studied as the candidate materials of substrate materials. For example, cubic perovskites has recently gained widespread usage as a substrate or buffer material for the heteroepitaxial growth of high temperature superconductors and other oxide thin films [16]. A perovskite-type crystal (orthorhombic distorted perovskites), NdGaO₃, was reported as a succeeded candidate for the GaN substrate [17]: (La,Sr)(Al,Ta)O₃ (LSAT) [18] and (RE,Sr)(Al,Ta)O₃ (RE, rare earth elements) [19], the mixed perovskite-type oxide, have very good characteristics to be a substrate since it has a fairly small lattice mismatch with GaN. In general, the semiconductor, which has zinc blende structure, can grow on the substrate or buffer layers with cubic structure. The recent success of fabricating large GaAs MESFETs on Si substrates using an SrTiO₃ (cubic perovskites) as buffer layer increases the interest of investigating cubic perovskites [20].

Many researchers try to design and synthesize new cubic perovskites used as substrate materials. Obviously, if new cubic perovskites compounds and their lattice constants can be predicted, it is helpful to design new substrate or buffer materials with cubic perovskite structure. Recently, the authors [21], a proposed model of lattice constant in cubic perovskites ABX₃ was obtained by using average ionic radii (rav), of ABX₃. So, it is of practical and emergent to find out regularities governing the formation of cubic perovskite-type oxides in order to seek for new buffer materials or substrates for compound semiconductor direct growth. We have investigated the regularities governing perovskites formation by using empirical structure map methods and a total 173 perovskite oxide systems. It is found that the octahedral factor (r_B/r_O) is as important as the tolerance factor (t), with regard to the formability of perovskites.

STRUCTURAL MAP METHOD

First, Mooser and Perason [22] applied a two-dimension graphic to study the stability of different compounds, the two factors they used were the difference of electronegativity between the cation and the anion and the average principle quantum number. They succeeded to discriminate the crystal structures of AB-type compounds, of AX_2 -type halides, and the metallic or non-metallic ternary fluorides ABX. Similar methods were called the structural map technology, and more parameters were used to draw the graphic. Muller and Roy [23] proposed to plot "structural map", which took the ionic radius of A and B as coordinates to study the distribution of different structures for many ternary structural families. Furthermore, the schematic distribution map of different

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crystal structure for $A^{+1}B^{+5}X_3$, $A^{+2}B^{+4}X_3$ and $A^{+3}B^{+3}X_3$ systems separately, were given by the same method [23, 24]. However, the criterion for perovskite formability was not discussed, possibly due to the lack of accurate data of crystal structure of some ABX₃ compounds at that time. The ionic radius is the most important ionic parameter that dominates the crystal structure of ionic compound. In this study, the same method will be used to find the regularities governing cubic perovskites formability. Prediction criterions for the formability of perovskites are obtained by using these two parameters tolerance factor and octahedral factor.

The ideal cubic structure form may be seen as a network of BX_6 octahedra, where all the octahedra are corner sharing. The *A* ions occupy the cubo-octahedral holes in between the octahedra. Many derivatives of the ideal structure are found and the distortion of the structure from cubic is often considered to be determined by the relative sizes of the different ions of the compound. The much used tolerance factor (t) is defined as

$$\mathbf{t} = \mathbf{r}_{\mathrm{A}} + \mathbf{r}_{\mathrm{X}} / \sqrt{2} \left(\mathbf{r}_{\mathrm{B}} + \mathbf{r}_{\mathrm{X}} \right) \tag{1}$$

where r_A, r_B and r_X are the ionic radii of A, B and X₃ respectively. t=1 corresponds to an ideal perovskite, while a t<1indicates tilting or rotation of the BX_6 octahedra. A t>1 indicates preference for hexagonal perovskite structures, where the octahedra at least to some extent share faces. The facesharing octahedra then form chains along the hexagonal c axis, bound to each other by A-X bonds. The face sharing octahedra give relatively short B-B distances, thus increasing the electrostatic repulsion between the B-site cations. Hexagonal stacking and face sharing is therefore introduced in stages with increasing size of the A cation. Alkaline-earthmetal manganese oxides show this importance of size well [25]. CaMnO₃ forms an orthorhombic derivative of the cubic structure with slightly tilted octahedra [26]. At high temperatures SrMnO₃ takes a cubic perovskite structure with cornersharing octahedra only (Fig. 1a) [27]. At low temperatures, on the other hand, SrMnO3 forms a four-layer hexagonal structure (Fig. 1b) with both face-sharing and corner-sharing octahedra corresponding to hexagonal and cubic stacking, respectively. BaMnO₃ forms a hexagonal structure with face sharing of octahedra only. The stabilization of the hexagonal structures at low temperatures has long been ascribed to the formation of metal-metal interactions across the shared face [28]. However, the Mn-Mn d-orbital overlap has recently been shown to be minimal [25, 29] Instead covalent interactions between manganese and oxygen atoms are indicated. Both the relative sizes of the cations and the covalency of the Mn-O bonds appear to be important for stabilizing the hexagonal structures of SrMnO3 and BaMnO3 at low temperatures [25, 29].

Tolerance factor (t) has been widely accepted as a criterion for the formation of the perovskite structure, many researchers have used it to discuss the cubic perovskites stability, and therefore, it is an important factor for the stability of cubic perovskites, so tolerance factor (t) constructs one axe of the structure map. Another important octahedron factor (r_B/r_O) [30] is as important as the tolerance factor to form cubic perovskites, so octahedron factor constructs another axe of the two-dimension structure map. Which are shown in Fig. (5).



Fig. (1a). Ideal cubic perovskite structure.



Fig. (1b). Four layer hexagonal perovskite structure.

RESULTS AND DISCUSSION

A total of 173 binary oxide systems are collected, as seen in Table 1, of which, 29 systems (denote "F") are found to have cubic perovskite structure, 144 systems (denote "NF")



Fig. (2). Perovskite formability in $(A^+B^{5+}X_3)$ oxide systems.



Fig. (3). Perovskite formability in $(A^{+2}B^{4+}X_3)$ oxide systems.



Fig. (4). Perovskite formability in $(A^{+3}B^{3+}X_3)$ oxide systems.

can not form cubic perovskite structure. It is well known, a crystal structure can change with variation of temperature and/or pressure. Compounds with other structure can, therefore, transform into cubic perovskite structure, and vice verse at different temperature and/or pressure. So, the criterion for classifying a forming system is that a compound of cubic perovskites is stabilized at room temperature and one atmosphere pressure. 173 perovskite-type oxides systems with their formability, ionic radius of constituent ions A and B, tolerance

factor and the octahedral factor (the ratio of radius of the small cation B over the radii of anion O) are listed in Table 1. The ionic radius of r_A , r_B and r_X (X = O⁻² is 1.35 Å) are taken from [5, 8, 21, 33]. As shown in Figs. (2-5), all perovskites and non-perovskites are located in two different regions, and a clear border between two kinds of compounds is identified. In the Fig. (5), the criterion of perovskite formability is, then, expressed by the following equations:

$$r_{\rm B}/r_{\rm O} = 0.433$$
 (2)

$$t = 1.032$$
 (3)

$$t = 0.857$$
 (4)

$$r_{\rm B}/r_{\rm O} = -1.327 \left\{ r_{\rm A} + r_{\rm O} / \sqrt{2} \left(r_{\rm B} + r_{\rm O} \right) \right\} + 1.781 \tag{5}$$



Fig. (5). Classification of cubic (ABO₃) perovskite oxides.

The tolerance factor is a widely used parameter in perovskites study, which takes all the ionic radii into consideration. And it is known that almost all perovskites have a t value ranging from 0.75 to 1.00. According to Gold-schmidt's point, t values of cubic perovskites are in the range of 0.8–0.9. From Fig. (5), it is indicated that t values of cubic perovskites, except BaMoO₃, are in the range of 0.857–1.032, which is wider than Goldschmidt's range. However, t = 0.857–1.032 is a necessary but not a sufficient condition for the formation of the cubic perovskite structure. The 85 systems, the t values of which are in the range (0.857–1.032), can not form cubic perovskite structure.

Octahedral factor is introduced into prediction of cubic perovskites formation. In our structure map (Fig. 5), the lowest limit of the octahedral factor for cubic perovskites formation is 0.433, and the highest r_B/r_O value of cubic perovskites is 0.704. It is well known that r_B/r_X value of octahedron BX₆ is ranging from 0.414 to 0.732 [30], the values of octahedron for all 30 cubic perovskites are in this range. However, octahedral factor (r_B/r_O value is not less 0.414) also is a necessary but not a sufficient condition for the formation of the cubic perovskite structure. The 91 systems in the range (r_B/r_O is not less 0.414) cannot form cubic perovskite structure as seen in Table 1. According to Galasso's report [1], LaVO₃ which belong to $A^{3+}B^{3+}O_3$ perovskites, have cubic perovskite

No.	Solids	$r_{A}(A)$ [5, 21]	$r_{B}(A)$ [5, 21]	Tolerance (t)	r_{B}/r_{X}	Formability*
1	CsIO ₃	1.88	0.95	0.993	0.704	F
2	CsNbO ₃	1.88	0.64	1.148	0.474	NF
3	CsVO ₃	1.88	0.54	1.028	0.341	NF
4	KUO ₃	1.64	0.76	1.002	0.563	F
5	KPaO ₃	1.64	0.78	0.993	0.578	F
6	KTaO ₃	1.64	0.64	1.062	0.474	NF
7	KNbO ₃	1.64	0.64	1.062	0.474	NF
8	KAsO3	1.64	0.46	1.168	0.341	NF
9	KVO ₃	1.64	0.54	1.119	0.400	NF
10	KPO ₃	1.64	0.38	1.222	0.281	NF
11	KSbO ₃	1.64	0.60	1.084	0.444	NF
12	KIO ₃	1.64	0.95	0.919	0.704	F
13	KBiO ₃	1.64	0.76	1.002	0.563	NF
14	NaTaO ₃	1.39	0.64	0.974	0.474	NF
15	NaAlO ₃	1.39	0.535	1.028	0.396	NF
16	NaWO ₃	1.39	0.62	0.983	0.459	NF
17	NaAsO ₃	1.39	0.46	1.067	0.341	NF
18	NaSbO ₃	1.39	0.60	0.994	0.444	NF
19	NaPO ₃	1.39	0.38	1.120	0.281	NF
20	NaBiO ₃	1.39	0.76	0.918	0.563	NF
21	NaNbO ₃	1.39	0.64	0.974	0.474	NF
22	NaUO ₃	1.39	0.76	0.918	0.563	NF
23	NaVO ₃	1.39	0.54	1.025	0.341	NF
24	LiNbO ₃	1.61	0.64	1.052	0.474	NF
25	LiTaO ₃	1.61	0.64	1.052	0.474	NF
26	LiVO ₃	1.61	0.54	1.107	0.400	NF
27	LiAsO ₃	1.61	0.46	1.156	0.341	NF
28	LiPO ₃	1.61	0.38	1.210	0.281	NF
29	LiSbO ₃	1.61	0.60	1.073	0.444	NF
30	LiBiO ₃	1.61	0.76	0.992	0.563	NF
31	RbPaO ₃	1.72	0.78	1.019	0.578	F
32	RbNbO ₃	1.72	0.64	1.091	0.474	NF
33	RbTaO ₃	1.72	0.64	1.091	0.474	NF
34	RbIO ₃	1.72	0.95	0.994	0.704	F
35	RbUO ₃	1.72	0.76	1.029	0.563	F
36	CuPO ₃	0.77	0.38	0.867	0.281	NF
37	TiSbO ₃	0.67	0.60	0.732	0.444	NF
38	AgBiO ₃	1.48	0.76	0.948	0.563	NF
39	AgVO ₃	1.48	0.54	1.059	0.341	NF
40	AgTaO ₃	1.48	0.64	1.006	0.474	NF
41	AgNbO ₃	1.48	0.64	1.006	0.474	NF

 Table 1.
 The Values of Ionic Radius, Tolerance Factor, Octahedral Factor and Formability of 173 Perovskite Solids

(Table 1) contd.						
No.	Solids	$r_{A}(A)$ [5, 21]	$r_{B}(A)$ [5, 21]	Tolerance (t)	r_{B}/r_{X}	Formability*
42	AgSbO ₃	1.48	0.60	1.026	0.444	NF
43	TlIO ₃	1.70	0.95	1.084	0.704	NF
44	BaFeO ₃	1.61	0.585	1.082	0.433	NF
45	BaMoO ₃	1.61	0.65	1.047	0.481	F
46	BaNbO ₃	1.61	0.68	1.031	0.504	F
47	BaSnO ₃	1.61	0.69	1.026	0.511	F
48	BaHfO ₃	1.61	0.71	1.016	0.526	F
49	BaZrO ₃	1.61	0.72	1.011	0.533	F
50	BaIrO ₃	1.61	0.625	1.060	0.463	NF
51	BaPbO ₃	1.61	0.775	0.985	0.574	F
52	BaTbO ₃	1.61	0.76	0.992	0.563	F
53	BaPrO ₃	1.61	0.85	0.951	0.630	F
54	BaCeO ₃	1.61	0.87	0.943	0.644	F
55	BaAmO ₃	1.61	0.85	0.951	0.630	F
56	BaNpO ₃	1.61	0.87	0.943	0.644	F
57	BaUO ₃	1.61	0.89	0.934	0.659	NF
58	BaPaO ₃	1.61	0.90	0.930	0.667	F
59	BaThO ₃	1.61	0.94	0.914	0.696	F
60	BaTiO ₃	1.61	0.605	1.071	0.448	NF
61	BaGeO ₃	1.61	0.530	1.113	0.393	NF
62	BaSiO ₃	1.61	0.40	1.196	0.296	NF
63	BaMnO ₃	1.61	0.53	1.113	0.393	NF
64	SrMnO ₃	1.44	0.53	1.049	0.393	NF
65	SrVO ₃	1.44	0.58	1.022	0.430	NF
66	SrFeO ₃	1.44	0.585	1.020	0.433	F
67	SrTiO ₃	1.44	0.605	1.009	0.448	F
68	SrTcO ₃	1.44	0.645	0.989	0.478	NF
69	SrMoO ₃	1.44	0.65	0.986	0.481	F
70	SrNbO ₃	1.44	0.68	0.972	0.504	F
71	SrSnO ₃	1.44	0.69	0.967	0.511	F
72	SrHfO ₃	1.44	0.71	0.958	0.526	F
73	SrTbO ₃	1.44	0.76	0.935	0.563	NF
74	SrAmO ₃	1.44	0.85	0.897	0.630	NF
75	SrPuO ₃	1.44	0.86	0.893	0.637	NF
76	SrCoO ₃	1.44	0.53	1.049	0.393	NF
77	SrZrO ₃	1.44	0.72	0.939	0.533	F
78	SrRuO ₃	1.44	0.68 ^a	0.972	0.504	F
79	SrSiO ₃	1.44	0.40	1.127	0.296	NF
80	SrGeO ₃	1.44	0.53	1.049	0.393	NF
81	SrMnO ₃	1.44	0.53	1.049	0.393	NF
82	SrCeO ₃	1.44	0.87	0.889	0.644	NF
83	SrPbO ₃	1.44	0.775	0.928	0.574	NF

No.	Solids	$r_{A}(Å)$ [5, 21]	$r_{B}(A)$ [5, 21]	Tolerance (t)	r_{B}/r_{X}	Formability*
84	CaVO ₃	1.34	0.58	0.986	0.430	NF
85	CaSiO ₃	1.34	0.40	1.087	0.296	NF
86	CaGeO ₃	1.34	0.53	1.012	0.393	NF
87	CaSnO ₃	1.34	0.69	0.932	0.511	NF
88	CaUO ₃	1.34	0.89	0.849	0.659	NF
89	CaZrO ₃	1.34	0.72	0.919	0.533	NF
90	CaPbO ₃	1.34	0.775	0.895	0.574	NF
91	CaMnO ₃	1.34	0.53	1.012	0.393	NF
92	CaTiO ₃	1.34	0.605	0.973	0.448	NF
93	CaCoO ₃	1.34	0.87	0.857	0.644	F
94	CoTiO ₃	0.745	0.605	0.900	0.448	NF
95	CoSiO ₃	0.745	0.40	0.847	0.296	NF
96	CoMnO ₃	0.745	0.53	0.788	0.393	NF
97	MgGeO ₃	0.72	0.53	0.867	0.393	NF
98	MgTiO ₃	0.72	0.605	0.892	0.448	NF
99	MgSnO ₃	0.72	0.69	0.718	0.511	NF
100	MgSiO ₃	0.72	0.40	0.836	0.296	NF
101	MnTiO ₃	0.83	0.605	0.928	0.448	NF
102	MnGeO ₃	0.83	0.53	0.820	0.393	NF
103	ZnTiO ₃	0.74	0.605	0.898	0.448	NF
104	ZnSiO ₃	0.74	0.40	0.830	0.296	NF
105	FeTiO ₃	0.78	0.605	0.912	0.448	NF
106	FeSiO ₃	0.78	0.40	0.843	0.296	NF
107	PbSiO ₃	1.19	0.40	1.026	0.296	NF
108	PbGeO ₃	1.19	0.53	0.955	0.393	NF
109	PbCeO ₃	1.19	0.87	0.809	0.644	NF
110	PbTiO ₃	1.19	0.605	0.919	0.448	NF
111	PbZrO ₃	1.19	0.72	0.868	0.533	NF
112	CdGeO ₃	0.95	0.53	0.865	0.393	NF
113	EuTiO ₃	1.23	0.670	0.903	0.496	NF
114	EuAlO ₃	1.23	0.535	0.968	0.396	NF
115	EuCrO ₃	1.23	0.615	0.928	0.456	NF
116	EuFeO ₃	1.23	0.645	0.914	0.478	NF
117	EuGaO ₃	1.23	0.620	0.926	0.459	NF
118	EuBO ₃	1.23	0.230	1.155	0.170	NF
119	CeAlO ₃	1.34	0.535	1.009	0.396	NF
120	CeVO ₃	1.34	0.640	0.956	0.474	NF
121	CeCrO ₃	1.34	0.615	0.968	0.456	NF
122	GdAlO ₃	1.22	0.535	0.964	0.396	NF
123	GdCrO ₃	1.22	0.615	0.925	0.456	NF
124	GdFeO ₃	1.22	0.645	0.911	0.478	NF
125	GdYO ₃	1.22	1.200	0.713	0.889	NF

(Table 1) contd.....

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No.	Solids	r _A (Å) [5, 21]	$r_{B}(A)$ [5, 21]	Tolerance (t)	$r_{\rm B}/r_{\rm X}$	Formability*
126	GdGaO ₃	1.22	0.620	0.922	0.459	NF
127	GdTiO ₃	1.22	0.670	0.900	0.496	NF
128	GdBO ₃	1.22	0.230	1.150	0.170	NF
129	LaAlO ₃	1.36	0.535	1.017	0.396	NF
130	LaCrO ₃	1.36	0.615	0.975	0.456	NF
131	LaFeO ₃	1.36	0.645	0.961	0.478	NF
132	LaGaO ₃	1.36	0.620	0.973	0.459	NF
133	LaRhO ₃	1.36	0.665	0.951	0.493	NF
134	LaTiO ₃	1.36	0.670	0.949	0.496	NF
135	LaVO ₃	1.36	0.640	0.963	0.474	NF
136	LaMnO ₃	1.36	0.645	0.961	0.478	NF
137	LaCoO ₃	1.36	0.545	1.011	0.404	NF
138	LaBO ₃	1.36	0.230	1.213	0.170	NF
139	NdAlO ₃	1.27	0.535	0.983	0.396	NF
140	NdCoO ₃	1.27	0.545	0.978	0.404	NF
141	NdCrO ₃	1.27	0.615	0.943	0.456	NF
142	NdFeO ₃	1.27	0.645	0.929	0.478	NF
143	NdMnO ₃	1.27	0.645	0.929	0.478	NF
144	NdTiO ₃	1.27	0.670	1.091	0.496	NF
145	NdVO ₃	1.27	0.640	1.166	0.474	NF
146	NdGaO ₃	1.27	0.620	0.940	0.459	NF
147	PrAlO ₃	1.30	0.535	0.994	0.396	NF
148	PrCrO ₃	1.30	0.615	0.954	0.456	NF
149	PrFeO ₃	1.30	0.645	0.939	0.478	NF
150	PrGaO ₃	1.30	0.620	0.951	0.459	NF
151	PrMnO ₃	1.30	0.645	0.939	0.478	NF
152	PrVO ₃	1.30	0.640	0.942	0.474	NF
153	SmAlO ₃	1.24	0.535	0.972	0.396	NF
154	SmCoO ₃	1.24	0.545	0.966	0.404	NF
155	SmVO ₃	1.24	0.640	0.920	0.474	NF
156	SmFeO ₃	1.24	0.645	0.918	0.478	NF
157	SmYO ₃	1.24	1.200	0.718	0.889	NF
158	SmCeO ₃	1.24	1.34	0.681	0.993	NF
159	SmTiO ₃	1.24	0.670	0.907	0.496	NF
160	SmBO ₃	1.24	0.230	1.159	0.170	NF
161	YAlO ₃	1.20	0.535	0.957	0.396	NF
162	YCrO ₃	1.20	0.615	0.918	0.456	NF
163	YFeO ₃	1.20	0.645	0.904	0.478	NF
164	YTiO ₃	1.20	0.670	0.893	0.496	NF
165	YBO ₃	1.20	0.230	1.141	0.170	NF
166	VCrO ₃	0.64	0.65	0.716	0.456	NF
167	VAlO ₃	0.64	0.535	0.746	0.396	NF

No.	Solids	r _A (Å) [5, 21]	$r_{B}(A)$ [5, 21]	Tolerance (t)	$\mathbf{r}_{\mathrm{B}}/\mathbf{r}_{\mathrm{X}}$	Formability*	
168	BiAlO ₃	1.03	0.535	0.893	0.396	NF	
169	BiGaO ₃	1.03	0.620	0.854	0.459	NF	
170	BiInO ₃	1.03	0.800	0.783	0.593	NF	
171	BiSmO ₃	1.03	1.24	0.650	0.919	NF	
172	BiFeO ₃	1.03	0.645	0.844	0.478	NF	
173	BiScO ₃	1.03	0.745	0.803	0.552	NF	
*F represents that binary oxide systems can form cubic perovskite							

(Table 1) contd.....

*NF represents that binary oxide systems can not form cubic perovskite,

structure previously, however, the later reports indicate that LaVO₃ and Medarde [31, 32], rare earth perovskite oxides, have orthorhombic structure [3, 34]. We have also found in Fig. (5) that the $A^{3+}B^{3+}O_3$ system does not show "cubic perovskites" region. Our results are good agreement with Medarde [31, 32], and may imply other criterion for cubic perovskites formability. In the Fig. (5), it can be seen that some systems of all 173 "non-cubic perovskites", including SrPbO₃, SrTbO₃, SrTcO₃, AgBiO₃, AgNbO₃ and BaUO₃ are wrongly classified in "cubic perovskites" region by the criterion mentioned above. However some points near the boundary between "cubic perovskites" and "non-cubic perovskites", as seen in Fig. (5), few points, representing like as AgNbO₃ (at 610°C) and AgBiO₃ just inside the boundary, which has distorted perovskite structure can transfer to cubic perovskite structure at 610°C [35].

CONCLUSION

We come to the conclusion that our model gives a simple and effective prediction criterion for cubic perovskites formability. New cubic perovskite structure compounds can be predicted by using this model, and their lattice constant can be predicted by a proposed relation of lattice constant in cubic perovskites, which was obtained in our previous study [21]. Using these models, we can seek for new cubic perovskites which lattice constant is close to compound semiconductor. Using these samples, regularities of formability of cubic perovskites are investigated by two empirical two-dimension structural map, One map is drawn by the ionic radii of cation A and B, another is spanned by octahedral factor (r_B/r_0) and the tolerance factor.

Through this study, the following conclusions are obtained:

- 1. In the R_A - R_B structural map (Figs. 2-4), the systems with perovskite and those non perovskite are distributed in distinctively different regions, there exists a clear boundary between these two kinds of samples.
- 2. Octahedral factor is as important as the tolerance factor for cubic perovskites formability.
- 3. Both tolerance factor and octahedral factor are a necessary but not sufficient condition for cubic perovskites formability. Using these two factors, the cubic perovskites formability can be reliably predicted.

4. In the structural map (Fig. 5) that is drawn by the tolerance factor and octahedral factor the points for cubic perovskites and those for non-cubic perovskites are located in different zones *via* clear boundary defined by Eqs. (2)–(5). These equations form the criteria for cubic perovskites formability.

The simple method presented in this work will be helpful to material scientists for finding new substrate or buffer materials in compound semiconductor epitaxy.

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